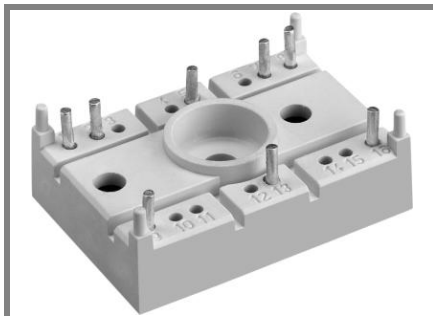


# SK 60 GAL 128



**SEMITOR<sup>®</sup> 2**

## IGBT Module

SK 60 GAR 128

SK 60 GAL 128

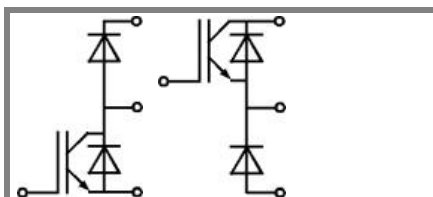
Target Data

### Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonding aluminium oxide ceramic (DBC)
- High short circuit capability
- SPT=Soft-Punch-Through technology
- $V_{ce(sat)}$  with positive coefficient

### Typical Applications

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

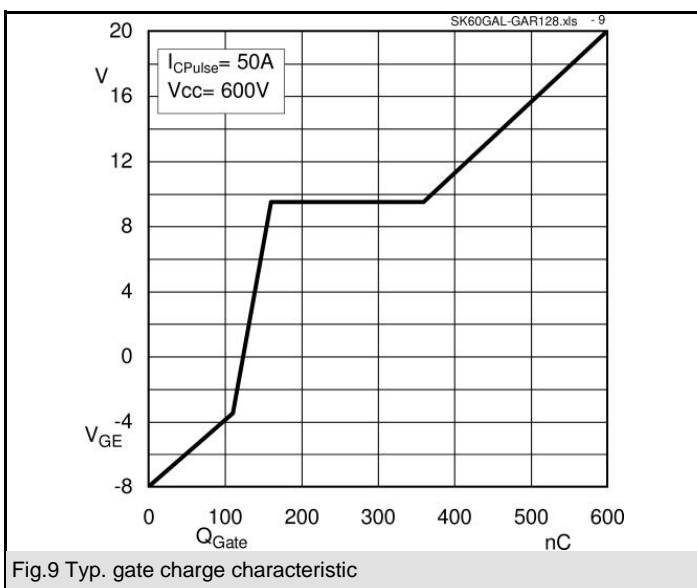
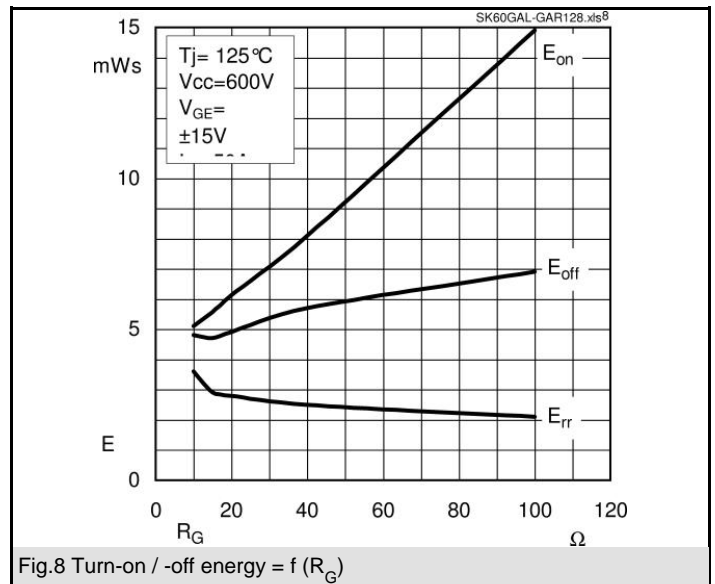
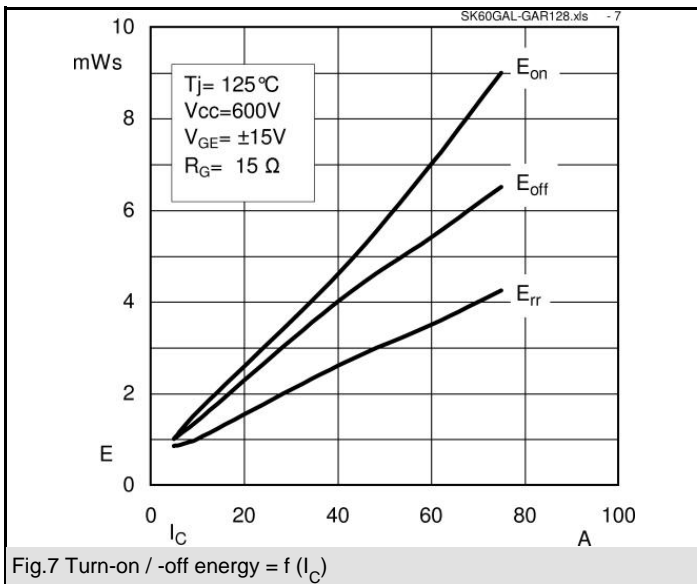
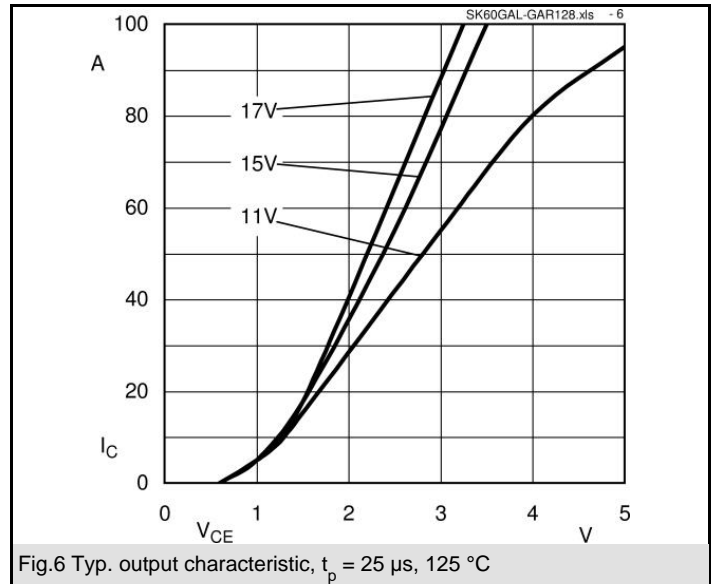
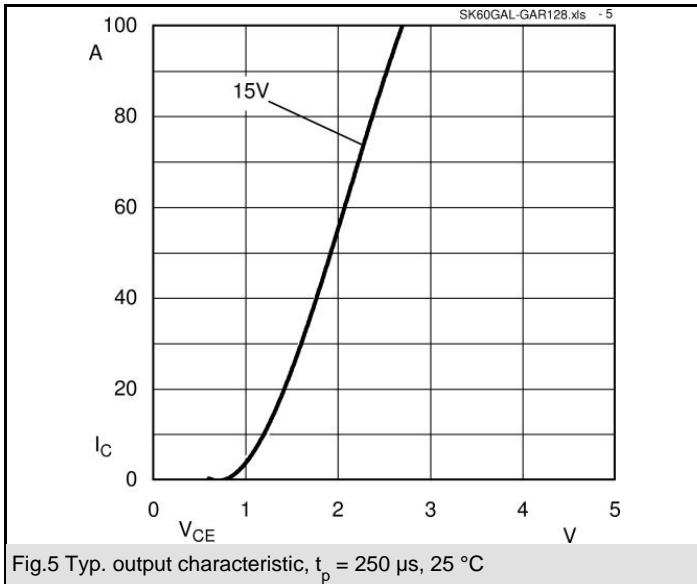


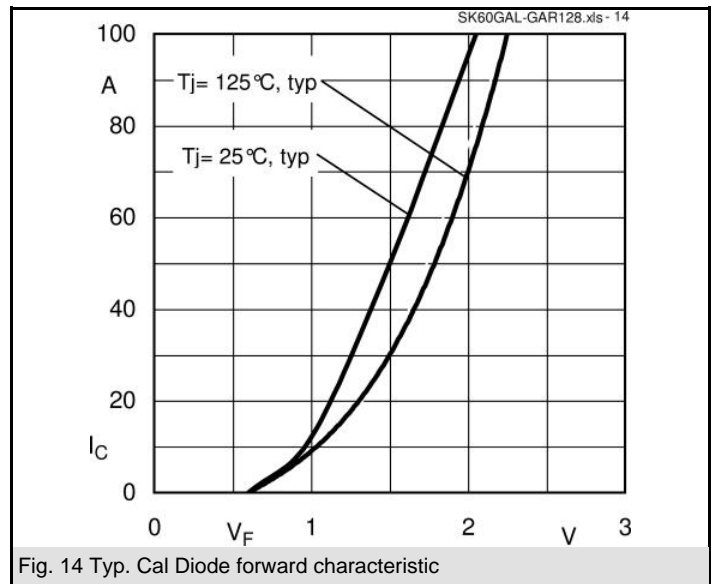
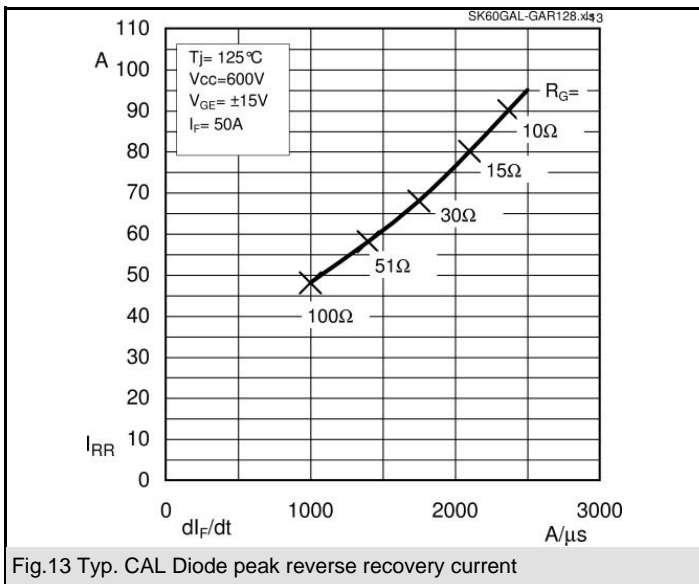
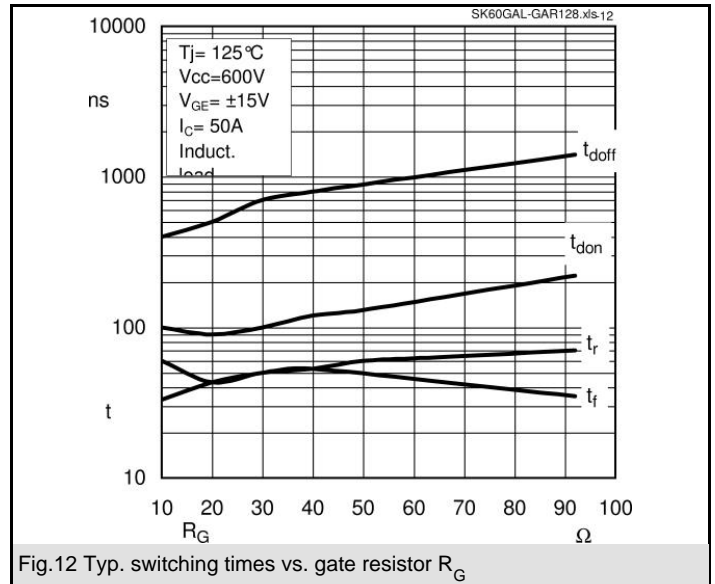
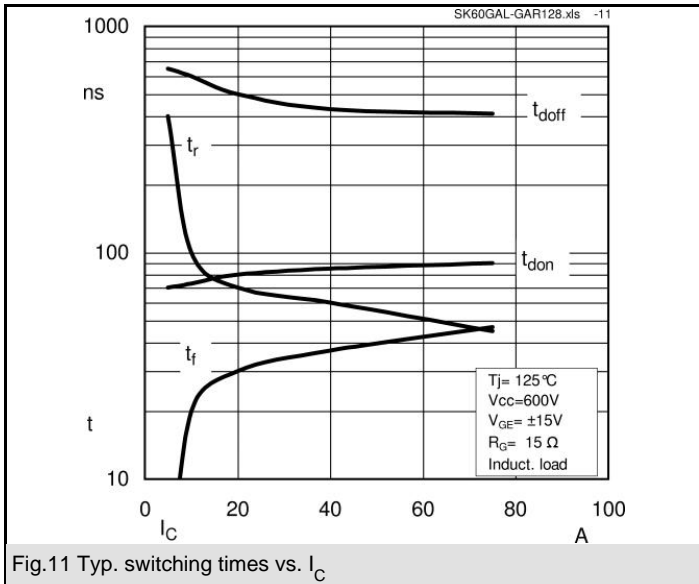
GAL

GAR

Absolute Maximum Ratings		$T_s = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$		1200	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_s = 25\text{ (80) }^\circ\text{C}$ ;	63 (44)	A
$I_{CM}$	$t_p < 1\text{ ms}$ ; $T_s = 25\text{ (80) }^\circ\text{C}$ ;	130 (90)	A
$T_j$		- 40 ... + 150	$^\circ\text{C}$
<b>Freewheeling CAL diode</b>			
$I_F$	$T_s = 25\text{ (80) }^\circ\text{C}$ ;	57 (38)	A
$I_{FM} = -I_{CM}$	$t_p < 1\text{ ms}$ ; $T_s = 25\text{ (80) }^\circ\text{C}$ ;	114 (38)	A
$T_j$		- 40 ... + 150	$^\circ\text{C}$
$T_{stg}$		- 40 ... + 125	$^\circ\text{C}$
$T_{sol}$	Terminals, 10 s	260	$^\circ\text{C}$
$V_{isol}$	AC 50 Hz, r.m.s. 1 min. / 1 s	2500 / 3000	V

Characteristics		$T_s = 25\text{ }^\circ\text{C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
$V_{CE(sat)}$	$I_C = 40\text{ A}$ , $T_j = 25\text{ (125) }^\circ\text{C}$		1,8 (1,94)		V
$V_{GE(th)}$	$V_{CE} = V_{GE}$ ; $I_C = 0,002\text{ A}$	4,5	5,5	6,5	V
$C_{res}$	$V_{CE} = 25\text{ V}$ ; $V_{GE} = 0\text{ V}$ ; 1 MHz		4,5		nF
$R_{th(j-s)}$	per IGBT per module			0,6	K/W K/W
$t_{d(on)}$	under following conditions: $V_{CC} = 600\text{ V}$ , $V_{GE} = \pm 15\text{ V}$		80		ns
$t_r$	$I_C = 50\text{ A}$ , $T_j = 125\text{ }^\circ\text{C}$		50		ns
$t_{d(off)}$	$R_{Gon} = R_{Goff} = 15\text{ }^\circ\Omega$		420		ns
$t_f$			40		ns
$E_{on} + E_{off}$	Inductive load		10,4		mJ
<b>Freewheeling CAL diode</b>					
$V_F = V_{EC}$	$I_F = 50\text{ A}$ ; $T_j = 25\text{ (125) }^\circ\text{C}$		2 (1,8)		V
$V_{(TO)}$	$T_j = (125)\text{ }^\circ\text{C}$		(1)	(1,2)	V
$r_T$	$T_j = (125)\text{ }^\circ\text{C}$		(16)	(22)	m $\Omega$
$R_{th(j-s)}$				0,9	K/W
$I_{RRM}$	under following conditions: $I_F = 50\text{ A}$ ; $V_R = 600\text{ V}$		40		A
$Q_{rr}$	$di_F/dt = -800\text{ A}/\mu\text{s}$		8		$\mu\text{C}$
$E_{off}$	$V_{GE} = 0\text{ V}$ ; $T_j = 125\text{ }^\circ\text{C}$		2		mJ
<b>Mechanical data</b>					
M1	mounting torque			2	Nm
w			19		g
Case	SEMITOR <sup>®</sup> 3		T 18		

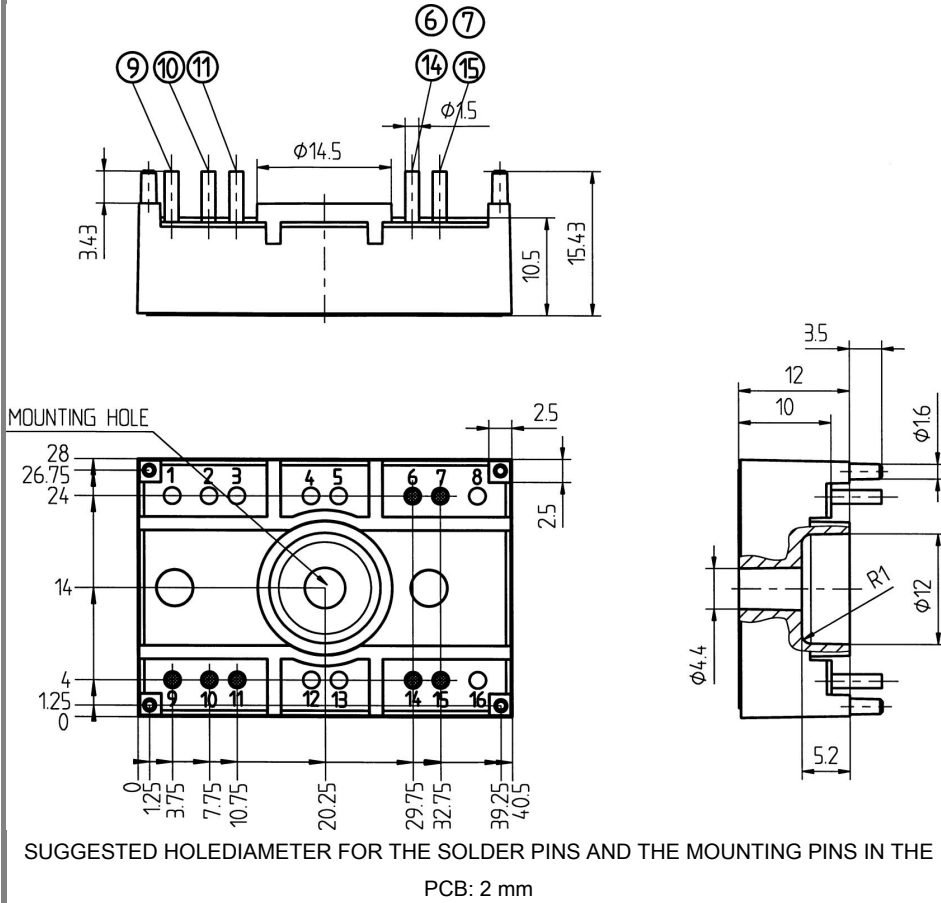




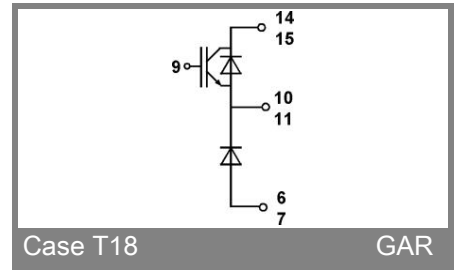
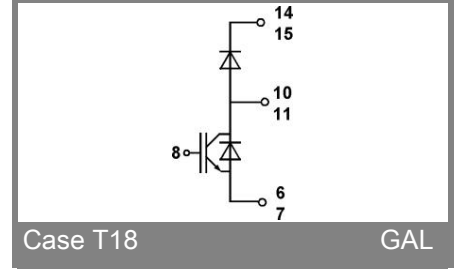
# SK 60 GAL 128

UL Recognized  
File no. E 63532

Dimensions in mm



Case T18



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.